

±

≡

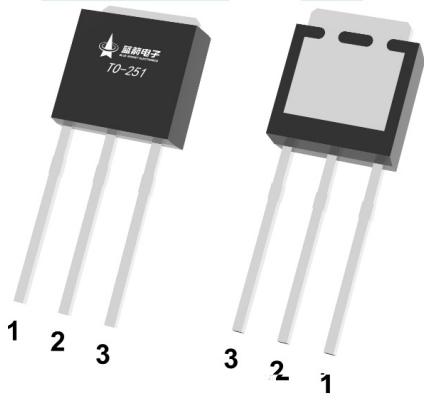
。

oD

→

G

OS





	℃		
	θ		
	θ		



		μ				
		μ				
						Ω



		Ω Ω				

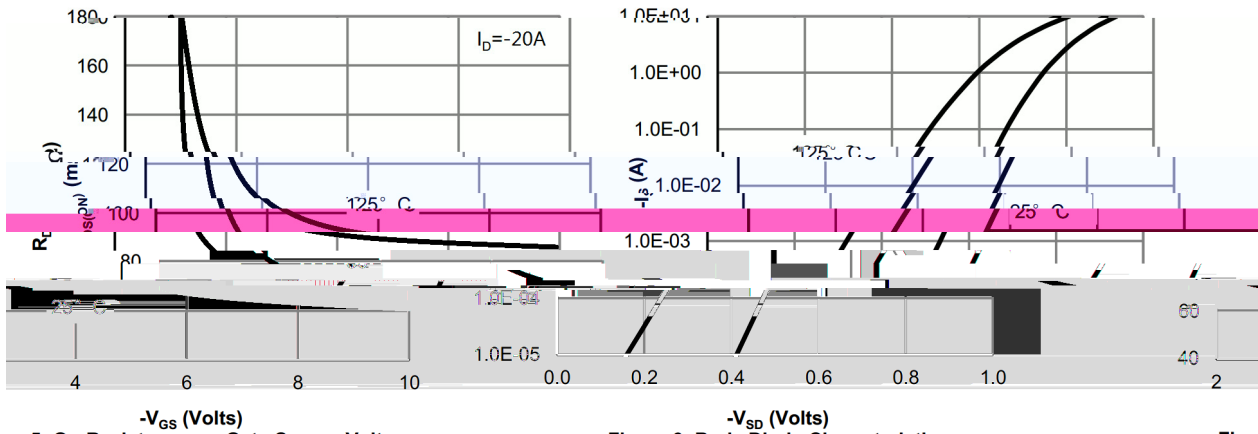
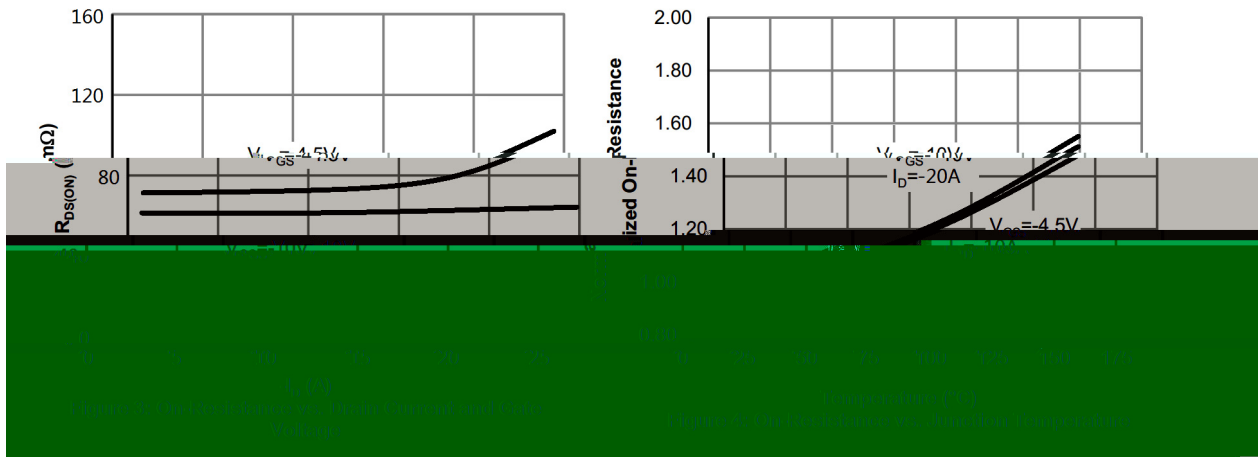
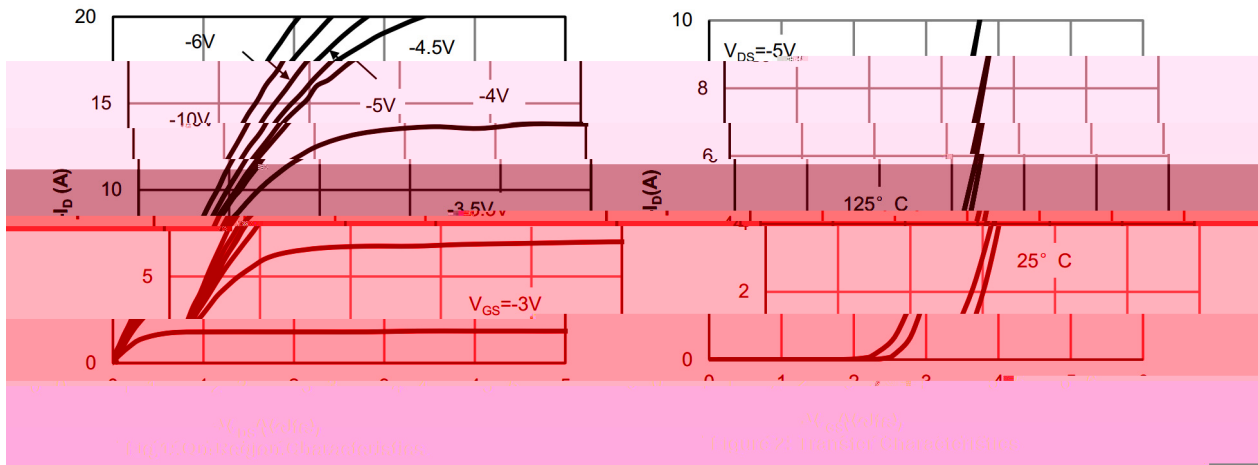


Figure 5: On-Resistance vs. Gate-Source Voltage

Figure 6: Body-Diode Characteristics

Figure

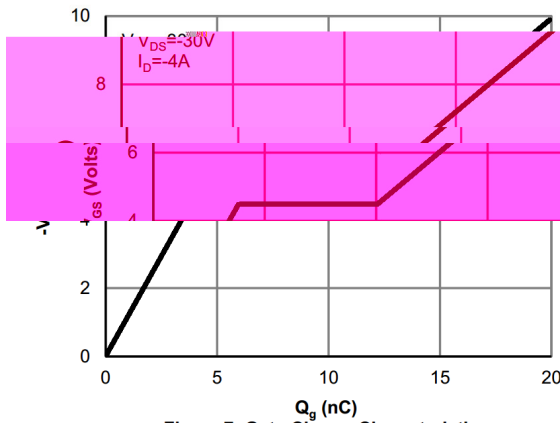


Figure 7: Gate-Charge Characteristics

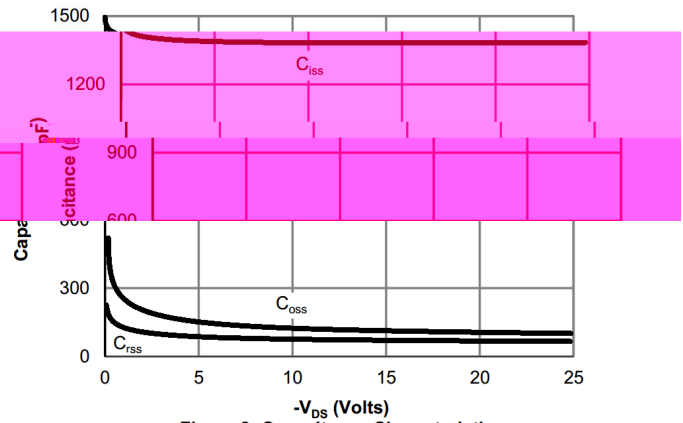


Figure 8: Capacitance Characteristics

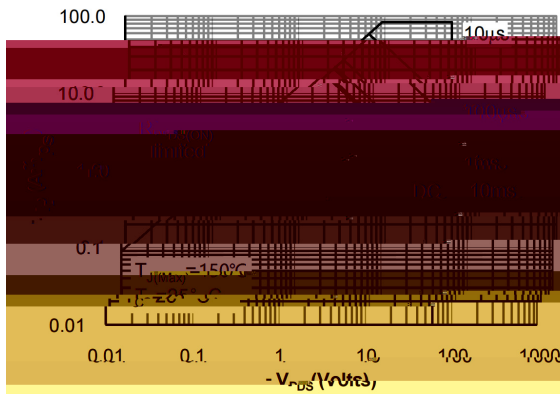


Figure 9: Maximum Forward Biased Safe Operating Area

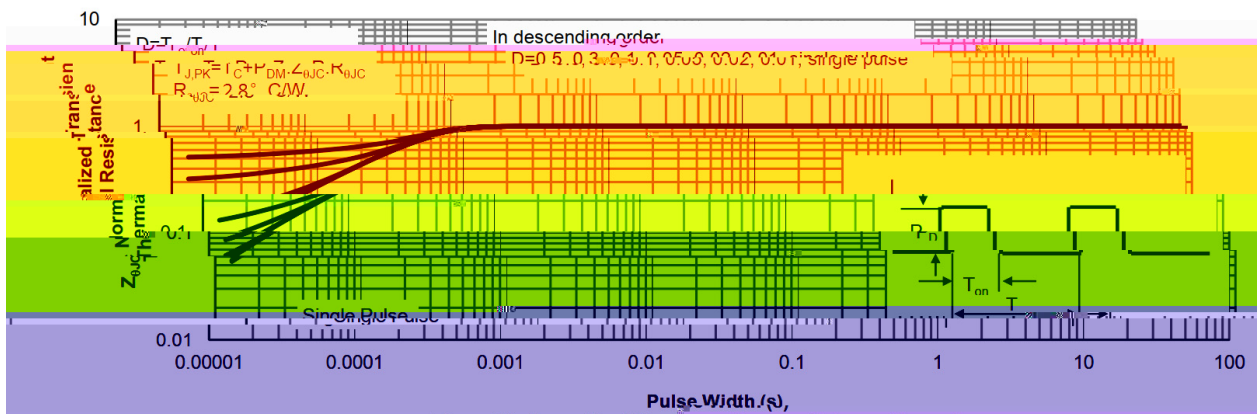
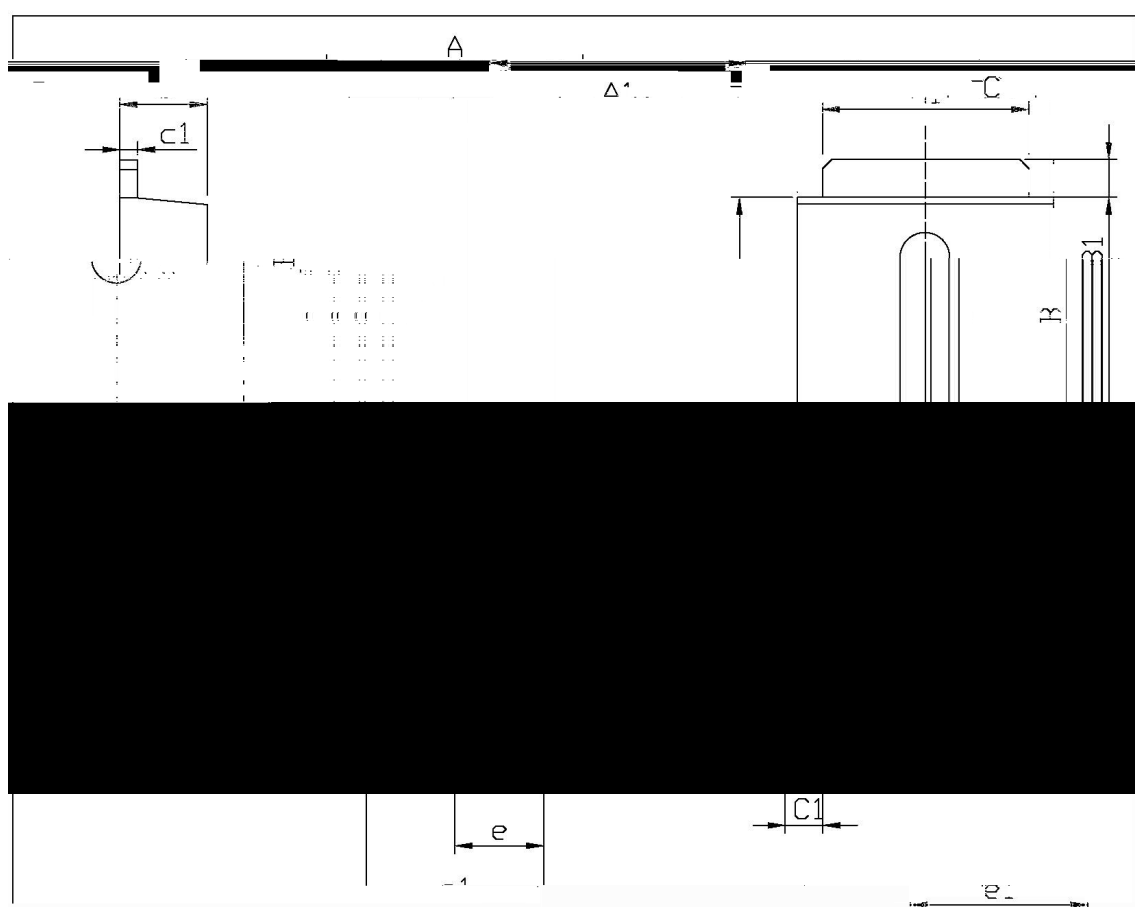


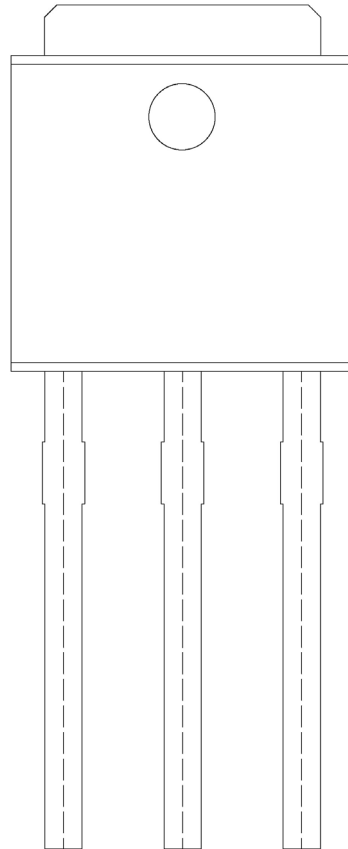
Figure 10: Normalized Maximum Transient Thermal Impedance

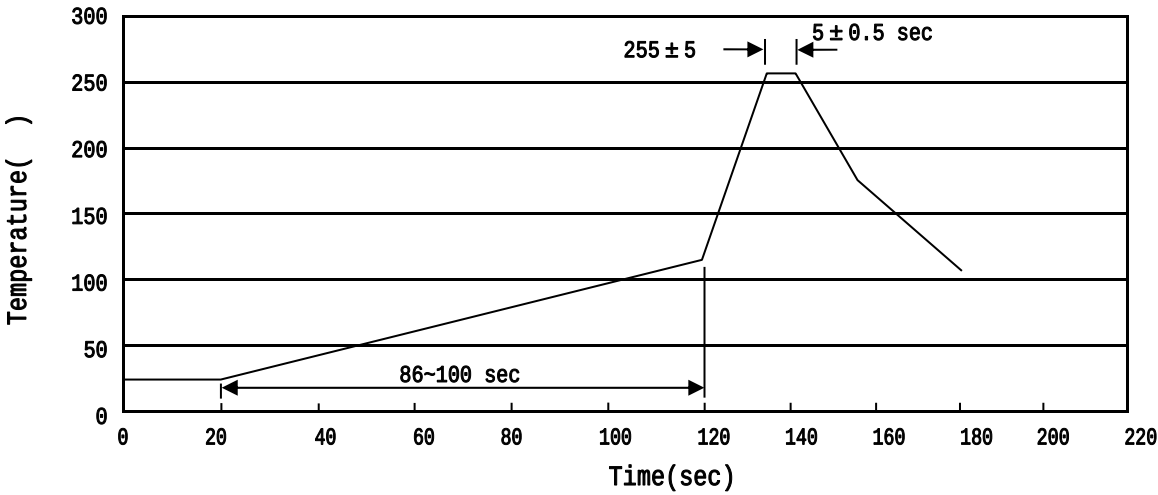


单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters		Symbol	
	Min	Max		Min	Max		
	6.40	6.75		0.50	0.50		
	5.10	5.50	b	9.00	9.40	A1	
	5.95	6.25	c	0.45	0.55	B=	
	B1	0.95	1.25	c1	0.45	0.55	
	C	2.20	2.40	e	2.24	2.34	
	4.73		C1	0.95	1.15	e1	4.43

TQ-251





	Units/Bag /	Bags/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Bag	Inner Box	Outer Box

	Units/Tube /	Tubes/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Tube	Inner Box	Outer Box